

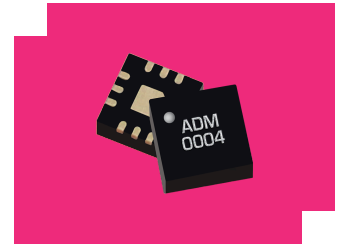
# ADM-10717PSM

## 18-40 GHz Broadband Low Noise Amplifier

### DEVICE OVERVIEW

#### General Description

The ADM-10717PSM is a broadband low noise amplifier covering 18 GHz to 40 GHz. Optimized for ultra-low DC power consumption in compact systems, it operates from a single 3 V supply at just 6 mA bias current, providing 16.7 dB of small-signal gain with a typical noise figure of 2.5 dB. The ADM-10717PSM requires no application circuit other than bypass capacitors on the DC supply lines, which simplifies integration and reduces board space. Packaged in a compact 3 mm QFN, it is well suited for wideband front-end applications that demand low power, moderate gain, and minimal added noise. Measured small-signal S-parameters are available to support accurate system simulation.



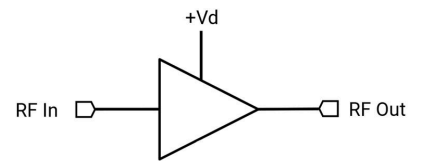
#### Features

- Broadband 18 to 40 GHz Operation
- Low Noise Figure, 2.5 dB Typical
- Low DC Power Consumption, 3V at 6 mA
- Single Supply Voltage
- No Sequencing Required

#### Applications

- SATCOM
- Phased array systems

#### Functional Block Diagram



#### Part Ordering Options

Part Number	Description	Package	Green Status	Product Lifecycle	Export Classification
ADM-10717PSM	18-40 GHz Broadband Low Noise Amplifier	QFN	REACH RoHS	Released	3A001.b.2.d
EVB-ADM-10717P	Evaluation Board, 18-40 GHz Broadband Low Noise Amplifier	EVB	REACH RoHS	Released	EAR99

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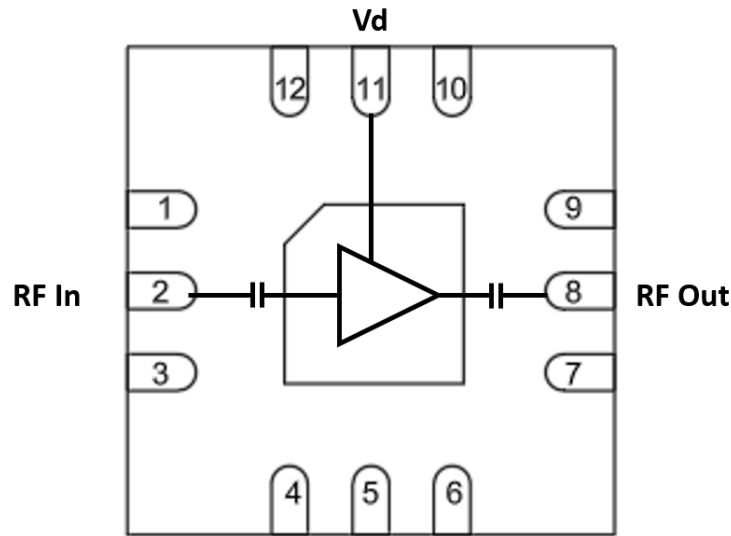
## Revision History

Revision Code	Revision Date	Comment
-	2025-10-20	Initial Release

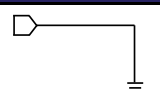
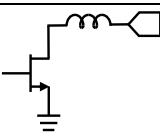
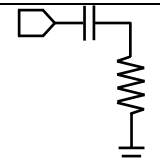
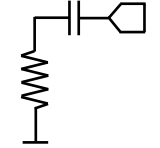
## Port Configuration and Functions

### Port Diagram

A port diagram of the ADM-10717PSM is shown below.



### Port Functions

Port	Function	Description	DC Equivalent Circuit
GND	Ground	Ground paddle and non-connected pins must be connected to a DC/RF ground potential with high thermal and electrical conductivity, and low inductance.	
Pin 11	Vd	Pin 11 is the DC bias supply for the amplifier. The voltage at this pin should be set to 3V for normal operation. This part requires an off-chip bypass capacitor of 0.1uF installed at this pin as close to the IC as possible. See applications circuit.	
Pin 1,3,4,5,6,7,9,10,12	Ground	These pins are not internally connected to the amplifier die. It is recommended to connect these pins to ground to provide RF isolation and mechanical stability. See the recommended landing pattern for details. Datasheet performance was measured with these pins connected to GND.	-
Pin 2	RF Input	Pin 2 is the amplifier's RF input pin. This port is internally matched to 50 Ohms and is internally DC blocked.	
Pin 8	RF Output	Pin 8 is the amplifier's RF output pin. This port is internally matched to 50 Ohms and is internally DC blocked.	

## Specifications

### Absolute Maximum Ratings

The Absolute Maximum Ratings indicate limits beyond which damage may occur to the device. If these limits are exceeded, the device may be inoperable or have a reduced lifetime. This amplifier is designed and characterized in a 50Ω system, and operation in a reflective environment can cause performance degradation.

Parameter	Maximum Rating	Unit
Maximum Operating Temperature	85	°C
Maximum Storage Temperature	150	°C
Max Junction Temperature for MTTF > 1E6 hours	175	°C
Minimum Operating Temperature	-40	°C
Minimum Storage Temperature	-65	°C
Positive Drain Supply Current (with RF Input)	19	mA
Positive Drain Supply Voltage (Vd)	6	V
RF Input Power	10	dBm

### Package Information

Parameter	Details	Rating
ESD	< 250 Volts	HBM Class 0
Dimensions	-	3 x 3 mm
Moisture Sensitivity Level	-	MSL 1

### Recommended Operating Conditions

The Recommended Operating Conditions indicate the limits, inside which the device should be operated, to guarantee the performance given in Electrical Specifications. Operating outside these limits may not necessarily cause damage to the device, but the performance may degrade outside the limits of the Electrical Specifications. For limits, above which damage may occur, see Absolute Maximum Ratings .

Parameter	Min	Nominal	Max	Unit
Ambient Temperature	-40	25	85	°C
Positive DC Current (Id) (No RF Input)	6	6	10	mA
Power Supply DC Voltage	3	3	5	V

### Sequencing Requirements

There are no sequencing requirements to power up or power down the amplifier.

**Electrical Specifications**

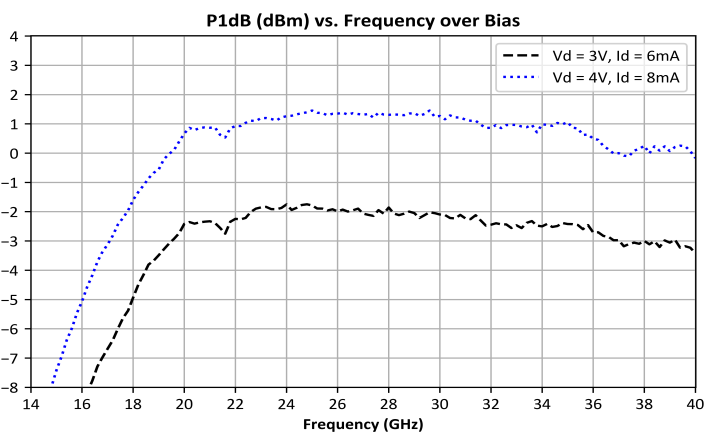
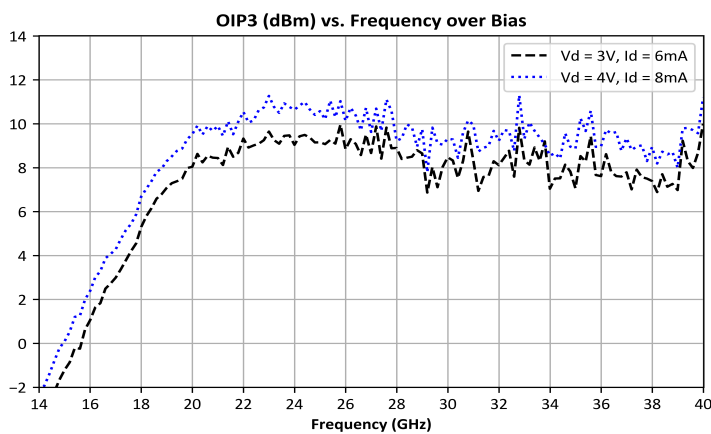
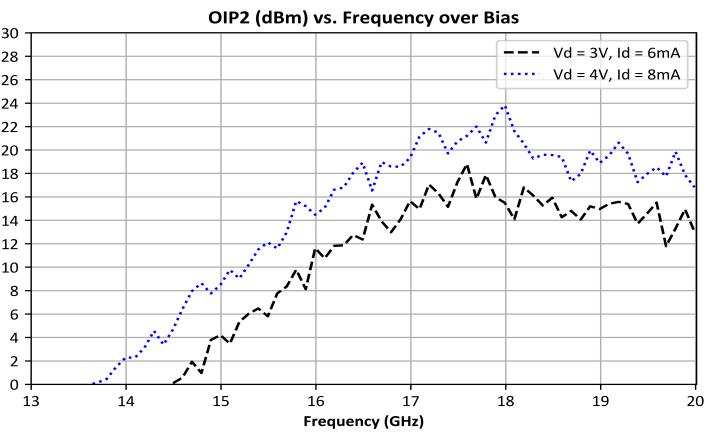
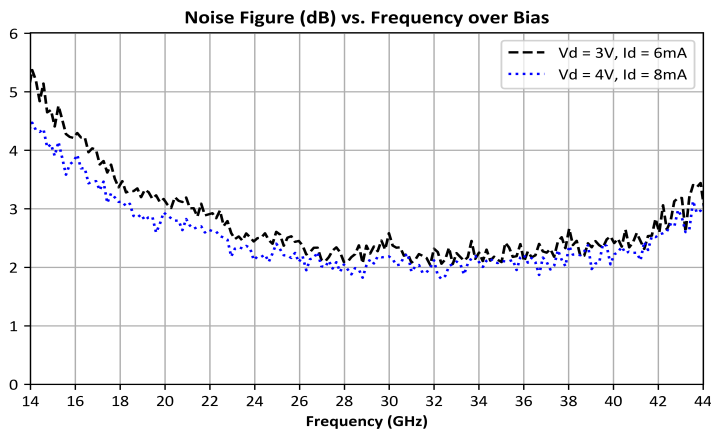
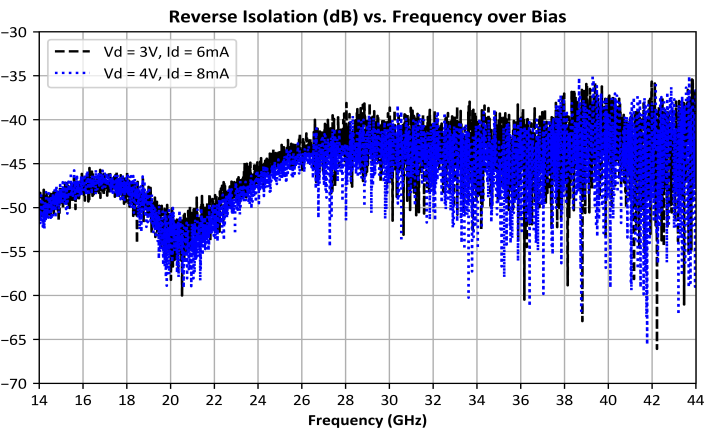
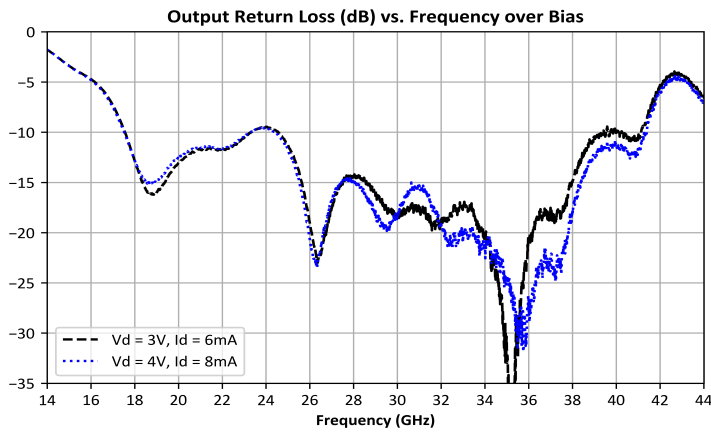
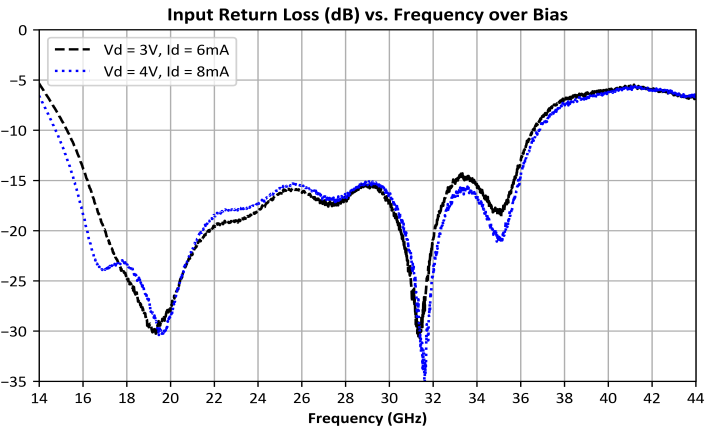
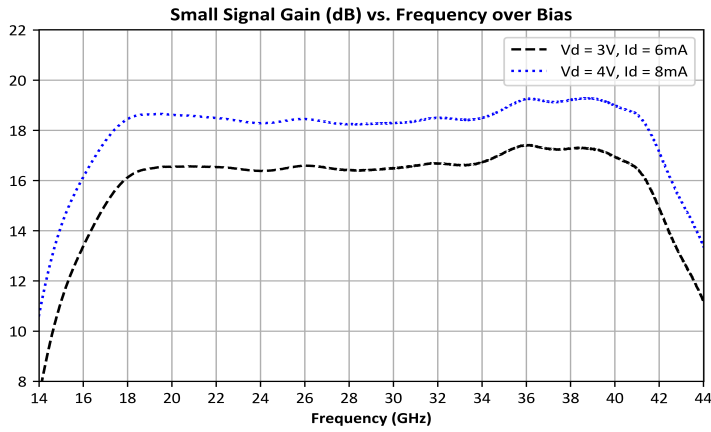
The electrical specifications apply at TA=+25°C in a 50Ω system. QFNs are 100% RF tested.

Parameter	Test Conditions	Minimum Frequency (GHz)	Maximum Frequency (GHz)	Min	Typ	Max	Unit
Small Signal Gain	3V bias, -30 dBm Input Power	18	40	-	16.7	-	dB
Input Return Loss	3V bias, -30 dBm Input Power	18	40	-	17	-	dB
Output Return Loss	3V bias, -30 dBm Input Power	18	40	-	16	-	dB
Reverse Isolation	3V bias, -30dBm Input Power	18	40	-	45	-	dB
Noise Figure	3V bias, -30 dBm Input Power	18	40	-	2.5	-	dB
Output P1dB	3V bias	18	40	-	-2.5	-	dBm
Output IP3	3V bias	18	40	-	8	-	dBm
Drain Current, Id <sup>1</sup>	3V bias	-	-	-	6	-	mA

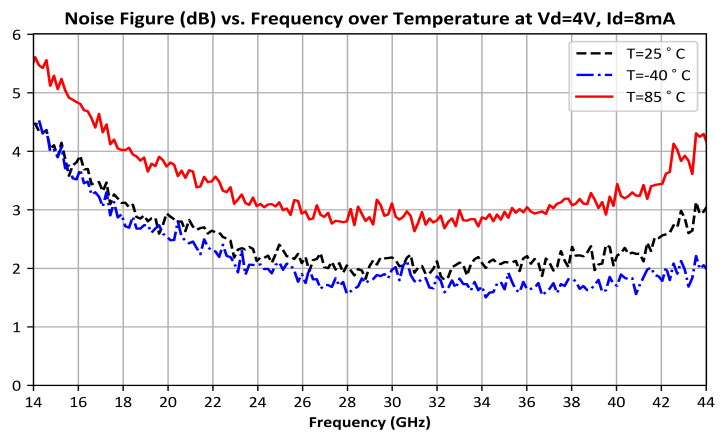
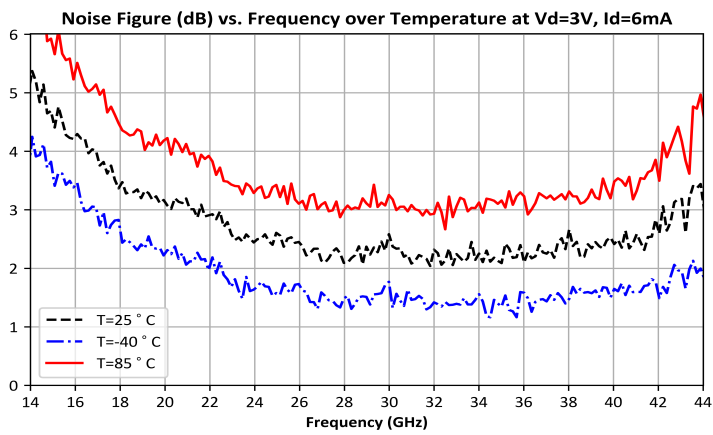
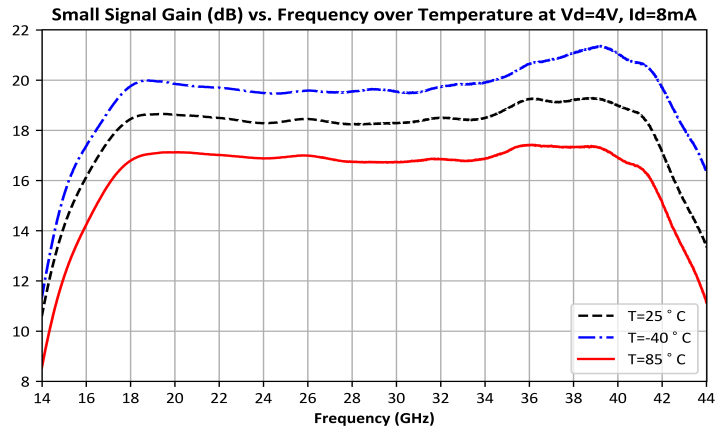
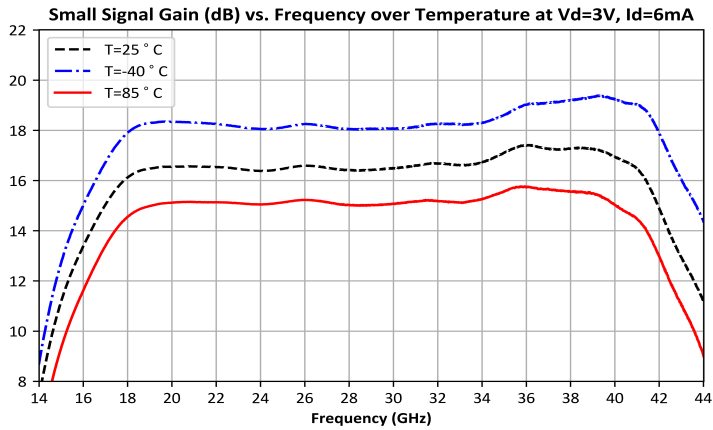
<sup>[1]</sup> Bias conditions for Id tested with no RF input power. Bias conditions presented as Vd.

### Typical Performance Plots (vs Bias)

Measurement data de-embedded using standard evaluation board.



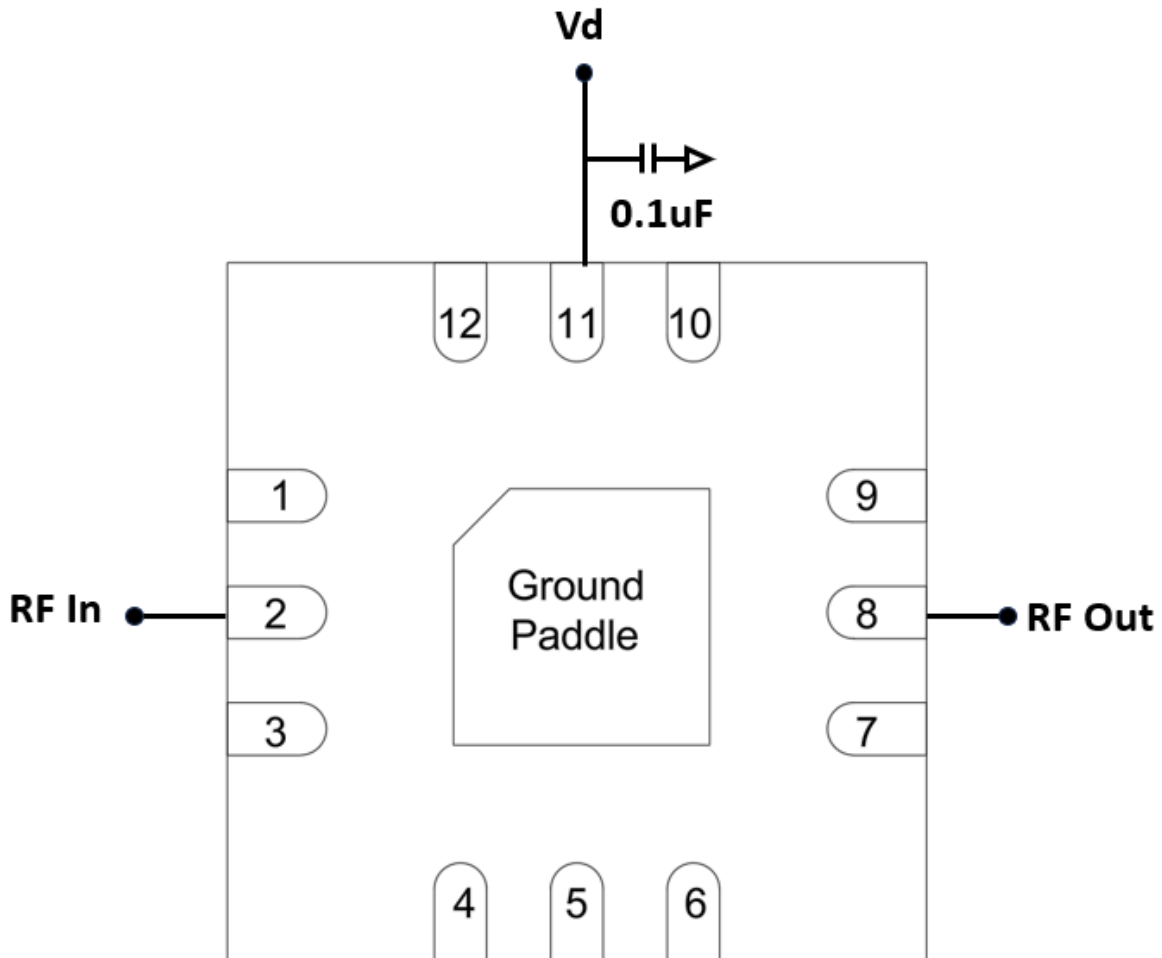
### Typical Performance Plots (vs Temperature)



### **Application Information**

Below is the recommended application circuit for the ADM-10717PSM. This is the configuration that is used to characterize this device. However, each PCB layout and environment are different which may require minor modifications of the biasing network. Please contact [support@markimicrowave.com](mailto:support@markimicrowave.com) for more information.

**Application Circuit**



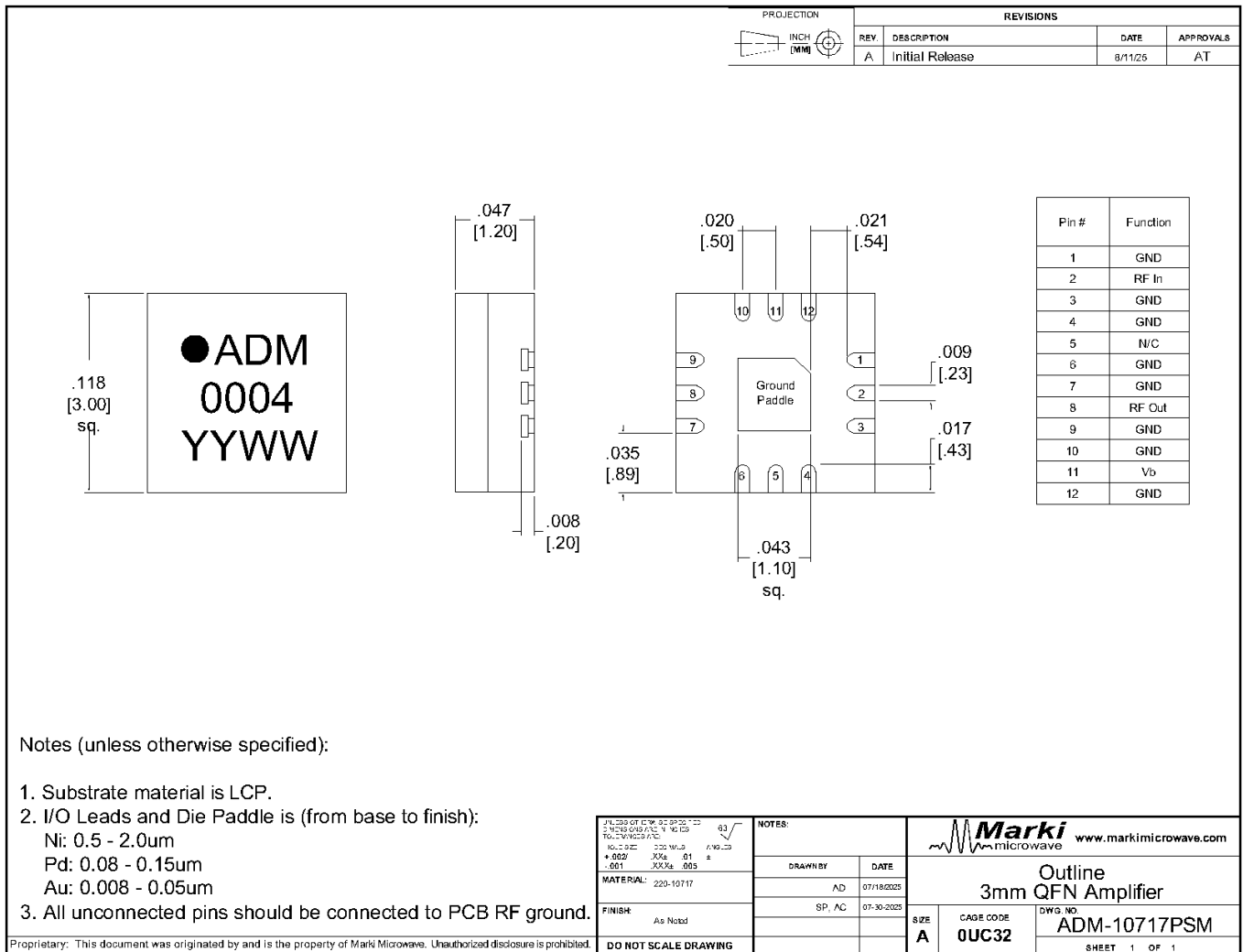
### Application Circuit Description

Above is the recommended application circuit for the ADM-10717PSM. DC drain voltage is supplied to the amplifier across a 0.1uF bypass capacitor to the Vd pin. The RF input and output ports are internally DC blocked.

### Mechanical Data

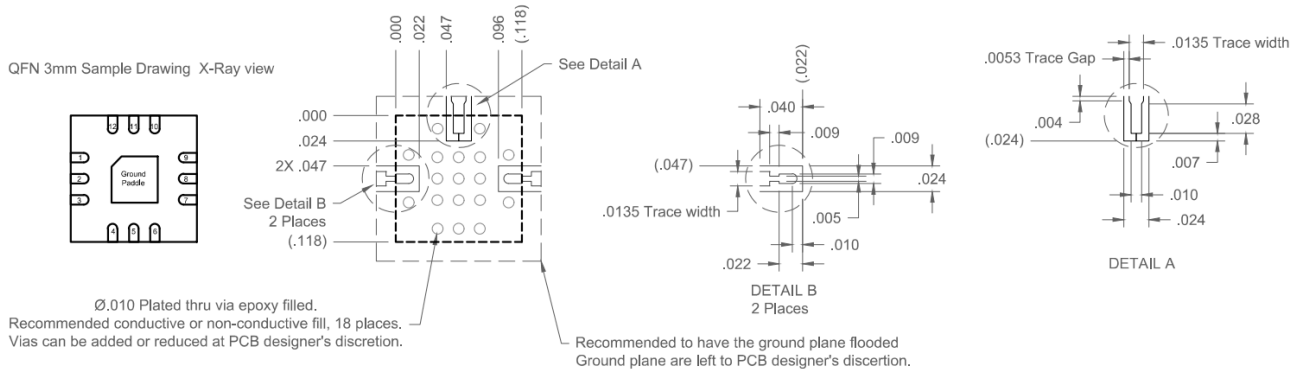
### Outline Drawing

Download : [Outline 2D Drawing](#)



### Footprint Image

Download : [Footprint Drawing](#)



The landing pattern is to be used on Rogers 4003,  
0.008" thick, ½ Oz Cu.



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